Design and Performance Evaluation of On-chip Antenna for Ultra Low Power Wireless Transceiver

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Abstract

In this paper, on-chip antennas applicable to ultra low power wireless transceiver are designed and evaluated. Using 0.18㎛ SiGe MMIC process, 4 types of antenna with $1 \times 1 \text{mm}^2$ dimensions are fabricated. The on-wafer measurement in a microwave probe station is conducted to measure the input VSWR and antenna performance of the designed on-chip antenna. Performance evaluation results show that developed antennas can be easily integrated into one chip RF transceiver for ubiquitous applications, including WPAN and human body communications.

Key words : On chip antenna, RF SoC, RFIC, SiGe, WPAN, Wireless Transceiver

I. Introduction

With the rapid progress of wireless multimedia communication technology, several pico and femto cell scale wireless systems which can conveniently deliver various kinds of information are suggested and implemented. Ubiquitous sensor network (USN), including WPAN(Wireless Personal Area Network) is one of the most promising concept for future mobile multimedia environment, and low cost RF microsystems and/or RF SoC (System on Chip) operating at required carrier frequencies are the key technology to build up USN system and services.

To implement ultra small size wireless transceiver for USN system, small antenna which can be easily integrated onto RF chips should be provided. Although conventional whip and helical antenna have excellent gain characteristics, they can not be used in USN wireless transceiver because of physical limitations such as large size and heavy weight\cite{4,5}. To cope with these limitations, embedded antenna using LTCC or ceramic technology have been widely studied and developed. But these type antennas also can not completely solve the physical limitations.

Recently, on-chip antennas which can be easily integrated into semiconductor wafer for RFIC chip/SoC are suggested and investigated. Integrated antennas directly coupled to the RF chip can offer potential advantages of low cost, reduced parasitic effects, simplified assembly, and design flexibility. Despite all these advantages, optimization of gain characteristics of on-chip antenna is necessary because the antenna performances such as gain and efficiency are basically dependent on the physical dimensions of antenna. In this paper, 4 types of SoC on-chip antennas with $1 \times 1 \text{mm}^2$ dimensions applicable to ubiquitous environments are studied and evaluated using 0.18㎛ SiGe MMIC process.

II. Small Microstrip Antenna

As shown in Fig.1, general structure of microstrip antenna is composed of the ground, substrate and patch element. Ground plane acts as reflector and ground for signal, and patch element radiate electrical energy into the space. Substrate is composed of dielectric materials and its height is usually from 0.005cm to 0.635cm, and conductor thickness is from 0.01778mm to 0.03556mm. Characteristic impedance of small microstrip patch antenna with height h, width W, conductor thickness t and effective dielectric constant $\varepsilon_r$ is given by Eq.\(1^{[3]-[5]}\).

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III. Design of On-chip Antennas

Empirical results show that on-chip patch antenna having physical dimensions below 1 mm$^2$ generally have operating frequency above 30GHz, so antenna geometry which can resonate below 30GHz should be carefully considered. As an example, patch antenna with $\varepsilon_r = 5$ and $W\times h = 1 \text{mm}$ resonate at 35.5GHz, so this type of antenna can not be used in lower frequency range\cite{2,3}.

To cope with these problems, 3 types of antenna geometries such as spiral, fractal and meander antenna are considered and evaluated. Fig. 2 represents general spiral antenna and its equivalent circuit.

![Fig. 2. Geometry and equivalent circuits of spiral antenna](image)

Circuit parameters of equivalent circuit of spiral antenna is given by Eq.(6).

$$R = \frac{4 R_{sheet} L}{W}$$  \hspace{1cm} (6)

$$R_{spi} = \frac{\rho_{spi} L}{W_{spi, thick}}$$

$$R_{spish} = \frac{\rho_{spi} L}{A}$$

$$R_{stub} = \frac{3 \rho}{8 D}$$

$$C_{stub} = \frac{\varepsilon_0 \varepsilon_r}{d} \frac{l w}{d}$$

where $L$ is total wire length, $D$ is outer dimension, $W$ is pitch width, $\rho$ is resistivity, $l$ is turn length, $w$ is spiral width, and $d$ is height between epi layer and bottom substrate, respectively.
Lower and upper operating frequency of spiral antenna depends on eddy current and electromagnetic mutual coupling, and resultant resonant frequency and inductance are given by Eq.(7).

\[
\begin{align*}
\omega_{\text{res}} &= \frac{18}{\mu_0} R_{\text{sheet}} \\
L_{\text{eddy}} &\approx \mu_0 L \ln \left( \frac{w}{W/4} \right) / \pi
\end{align*}
\]

In this work, 0.18μm SiGe RFIC foundry of ST microns is used to implement on-chip antenna and its stack geometry of layer structure is shown in Fig. 3. In order to easily adjust the resonant frequency of antenna, 4 types of antenna are designed and simulated using HFSS antenna simulator.

Fig. 4 shows the designed antenna patterns with different resonant frequencies, in which antenna 1 is a spiral antenna without grounding (f_r =12.8GHz), antenna 2 is a spiral antenna with grounding (f_r =12.8GHz), antenna 3 is a fractal antenna(f_r =9.7GHz), and antenna 4 is a meander antenna(f_r =19GHz), respectively.

E field patterns and resonance characteristics of each antenna are shown in Fig.5 ~ Fig.8.

Fig. 5 shows the characteristic of spiral antenna without grounding and Fig. 6 shows the characteristic of spiral antenna with grounding. Fig. 7 shows the characteristic of fractal antenna and Fig 8 shows that of the meander antenna.

![Fig. 3. Layer structure of 0.18 μm SiGe process chip](image)

![Fig. 4. Layout of designed antenna patterns](image)

![Fig. 5. Characteristics of spiral antenna without grounding](image)

![Fig. 6. Characteristics of spiral antenna with grounding](image)

![Fig. 7. Characteristics of fractal antenna](image)
(a) E field pattern  (b) Resonant frequency $f_r=12.8$GHz

**Fig. 8. Characteristics of meander antenna**

**IV. Performance Evaluation**

To evaluate antenna performance, each antenna is fabricated using ST microns 0.18um SiGe foundry and each antenna has 1x1mm$^2$ physical dimension. Fig. 9 is the photograph of fabricated antenna and on-wafer measurement in a microwave probe station is conducted to measure the input RL(Return Loss) and antenna performance.

![SEM photograph of fabricated antennas](image)

**Fig. 9. SEM photographs of fabricated antennas**

Fig.10 shows the resonant characteristics of spiral antenna without grounding. Figure shows that this antenna resonates at 2GHz and 15GHz which differ 2.2GHz from the simulated result.

Fig. 11 shows resonant characteristic of spiral antenna with grounding. As shown in the figure, this type antenna is very difficult to resonate in desired frequency and suffer high radiation loss due to the grounding effect.

Fig. 12 shows the measured return loss and impedance of fractal antenna which resonates dual frequencies at 7GHz and 21GHz, respectively. These dual band operation capability is originated from fractal patterns and may very useful in designing multiband transceiver such as MIMO(Multiple Input Multiple Output) applications.

Fig. 13 is the characteristic of meander antenna with 13GHz resonant frequency which differ 6GHz from the designed value(13GHz). This effect may comes from an insufficient energy coupling as shown in Fig. 8.

The absolute power gain performances of the antenna will be reported in the next paper, using on-wafer measurement technique presented in [5].
V. Conclusions

In this paper, 4 types of on-chip antennas to implement ultra low power RF SoC transceiver are studied and simulated including spiral, fractal and meander antenna. To evaluate these antennas, each antenna is fabricated using ST microns 0.18um SiGe foundry and their performances are measured. Measured results show that designed antennas can be easily integrated into RFIC chip/SoC to use for USN and MIMO applications.

As shown in the results, there exist some discrepancy between theoretical estimation and practical results. These discrepancies may come from the facts that we cannot exactly interpret layer structure, material coefficient and errors in manufacturing process. To improve and optimize the performance of on-chip antenna, methodology which can fully count these effects should be provided.

References


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<Research Interests>Mobile Communication and Components, Digital Broadcasting, WPAN, USN & RFID, Human Body Communications